

Data sheet acquired from Harris Semiconductor SCHS145E

CD54HC132, CD74HC132, CD54HCT132

High-Speed CMOS Logic Quad 2-Input NAND Schmitt Trigger

August 1997 - Revised March 2004

Features

- · Unlimited Input Rise and Fall Times
- Exceptionally High Noise Immunity
- Typical Propagation Delay: 10ns at $V_{CC} = 5V$, $C_L = 15pF$, $T_A = 25^{\circ}C$
- Fanout (Over Temperature Range)
- Wide Operating Temperature Range ...-55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: N_{IL} = 37%, N_{IH} = 51% of V_{CC} at V_{CC} = 5V
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility,
 V_{IL}= 0.8V (Max), V_{IH} = 2V (Min)
 - CMOS Input Compatibility, $I_I \le 1\mu A$ at V_{OL} , V_{OH}

Description

The 'HC132 and 'HCT132 each contain four 2-input NAND Schmitt Triggers in one package. This logic device utilizes silicon gate CMOS technology to achieve operating speeds similar to LSTTL gates with the low power consumption of standard CMOS integrated circuits. All devices have the ability to drive 10 LSTTL loads. The HCT logic family is functionally pin compatible with the standard LS logic family.

Ordering Information

PART NUMBER	TEMP. RANGE (°C)	PACKAGE
CD54HC132F3A	-55 to 125	14 Ld CERDIP
CD54HCT132F3A	-55 to 125	14 Ld CERDIP
CD74HC132E	-55 to 125	14 Ld PDIP
CD74HC132M	-55 to 125	14 Ld SOIC
CD74HC132MT	-55 to 125	14 Ld SOIC
CD74HC132M96	-55 to 125	14 Ld SOIC
CD74HCT132E	-55 to 125	14 Ld PDIP
CD74HCT132M	-55 to 125	14 Ld SOIC
CD74HCT132MT	-55 to 125	14 Ld SOIC
CD74HCT132M96	-55 to 125	14 Ld SOIC

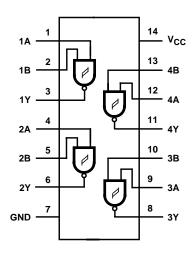
NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel. The suffix T denotes a small-quantity reel of 250.

Pinout

CD54HC132, CD54HCT132 (CERDIP) CD74HC132, CD74HCT132 (PDIP, SOIC) TOP VIEW

1A 1 14 V_{CC}
1B 2 13 4B
1Y 3 12 4A
2A 4 11 4Y
2B 5 10 3B
2Y 6 9 3A
GND 7 8 3Y

Functional Diagram

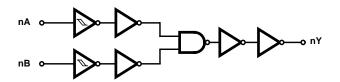


TRUTH TABLE

INP	INPUTS						
nA	nB	nY					
L	L	Н					
L	Н	Н					
Н	L	Н					
Н	Н	L					

H = High Voltage Level, L = Low Voltage Level

Logic Symbol



Absolute Maximum Ratings

DC Supply Voltage, V_{CC} -0.5V to 7V DC Input Diode Current, I_{IK} For $V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$ ± 20 mA DC Output Diode Current, I_{OK} DC Output Source or Sink Current per Output Pin, IO

Thermal Information

Thermal Resistance (Typical, Note 1)	θ_{JA} (oC/W)
E (PDIP) Package	80
M (SOIC) Package	86
Maximum Junction Temperature	150 ^o C
Maximum Storage Temperature Range	65°C to 150°C
Maximum Lead Temperature (Soldering 10s)	300°C
(SOIC - Lead Tips Only)	

Operating Conditions

Temperature Range (T _A)	55°C to 125°C
Supply Voltage Range, V _{CC}	
HC Types	2V to 6V
HCT Types	4.5V to 5.5V
DC Input or Output Voltage, $V_I, V_O \dots$	\ldots . 0V to VCC

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

1. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

			TEST CONDITIONS			25°C		-40°C TO 85°C		-55°C TO 125°C					
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS			
HC TYPES															
Input Switch Points	V _T +	-	-	2	0.7	-	1.5	0.7	1.5	0.7	1.5	٧			
(Note 2)				4.5	1.7	-	3.15	1.7	3.15	1.7	3.15	>			
				6	2.1	-	4.2	2.1	4.2	2.1	4.2	V			
	V _T -	-	-	2	0.3	-	1	0.3	1	0.3	1	٧			
				4.5	0.9	-	2.2	0.9	2.2	0.9	2.2	>			
				6	1.2	-	3	1.2	3	1.2	3	V			
	V _H			2	0.2	-	1	0.2	1	0.2	1	٧			
				4.5	0.4	-	1.4	0.4	1.4	0.4	1.4	>			
				6	0.6	1	1.6	0.6	1.6	0.6	1.6	V			
High Level Output	V _{OH}	V _T + or	-0.02	2	1.9	ı	-	1.9	-	1.9	-	V			
Voltage CMOS Loads		V _T -	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	٧			
			-0.02	6	5.9	1	-	5.9	-	5.9	-	V			
High Level Output		1				-4	4.5	3.98	-	-	3.84	-	3.7	-	٧
Voltage TTL Loads			-5.2	6	5.48	-	-	5.34	-	5.2	-	٧			
Low Level Output	V _{OL}	V _T + or	0.02	2	-	-	0.1	-	0.1	-	0.1	V			
Voltage CMOS Loads		V _T -	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V			
			0.02	6	-	-	0.1	-	0.1	-	0.1	V			
Low Level Output]		4	4.5	-	-	0.26	-	0.33	-	0.4	V			
Voltage TTL Loads			5.2	6	-	-	0.26	-	0.33	-	0.4	V			

DC Electrical Specifications (Continued)

		TEST CONDITIONS				25°C		-40°C T	O 85°C	-55°C TO 125°C		
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	TYP	МАХ	MIN	MAX	MIN	MAX	UNITS
Input Leakage Current	II	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μА
Quiescent Device Current	Icc	V _{CC} or GND	0	6	-	-	2	-	20	-	40	μА
HCT TYPES	•											<u> </u>
Input Switch Points	V _T +	-	-	4.5	1.2	-	1.9	1.2	1.9	1.2	1.9	V
(Note 2)				5.5	1.4	-	2.1	1.4	2.1	1.4	2.1	V
	V _T -	-	-	4.5	0.5	-	1.2	0.5	1.2	0.5	1.2	V
				5.5	0.6	-	1.4	0.6	1.4	0.6	1.4	V
	V _H	-	-	4.5	0.4	-	1.4	0.4	1.4	0.4	1.4	V
				5.5	0.4	-	1.5	0.4	1.5	0.4	1.5	V
High Level Output Voltage CMOS Loads	-	V _T + or V _T -	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V _{OL}	V _T + or V _T -	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	II	V _{CC} and GND	-	5.5	-	-	±0.1	-	±1	-	±1	μА
Quiescent Device Current	Icc	V _{CC} or GND	0	5.5	-	-	2	-	20	-	40	μА
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI _{CC} (Note 3)	V _{CC} - 2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μА

- 2. Hysteresis definition, characteristic and test setup see Test Circuits and Waveforms
- 3. For dual-supply systems theoretical worst case (V_I = 2.4V, V_{CC} = 5.5V) specification is 1.8mA.

HCT Input Loading Table

INPUT	UNIT LOADS					
nA, nB	0.6					

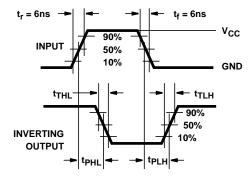
NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Specifications table, e.g. $360\mu A$ max at $25^{\circ}C$.

Switching Specifications Input t_{r} , $t_{f} = 6 \text{ns}$

		TEST	v _{cc}		25°C		-40°C T	O 85°C	-55°C TO 125°C		
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES											
Propagation Delay	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	125	-	156	-	188	ns
A, B to Y (Figure 1)			4.5	-	-	25	ı	31	-	38	ns
			6	-	-	21	-	27	-	32	ns
Propagation Delay A, B to Y	t _{TLH} , t _{THL}	C _L = 15pF	5	-	10	-	-	-	-	-	pF
Transition Times (Figure 1)	t _{TLH} , t _{THL}	C _L = 50pF	2	-	-	75	-	95	-	110	ns
			4.5	-	-	15	-	19	-	22	ns
			6	-	-	13	-	16	-	19	ns
Input Capacitance	C _I	-	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 4, 5)	C _{PD}	-	5	-	30	-	=	-	-	-	pF
HCT TYPES											
Propagation Delay A, B to Y (Figure 2)	t _{PHL} , t _{PHL}	C _L = 50pF	4.5	-	-	33	-	41	-	50	ns
Propagation Delay A, B to Y	t _{PLH} , t _{PHL}	C _L = 15pF	5	-	13	-	-	-	-	-	pF
Transition Times (Figure 2)	t _{TLH} , t _{THL}	C _L = 50pF	4.5	-	-	15	-	19	-	22	ns
Input Capacitance	C _I	-	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 4, 5)	C _{PD}	-	5	-	30	-	-	-	-	-	pF

- 4. $C_{\mbox{\scriptsize PD}}$ is used to determine the dynamic power consumption, per gate.
- 5. $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$ where f_i = input frequency, C_L = output load capacitance, V_{CC} = supply voltage.

Test Circuits and Waveforms



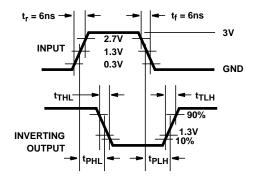


FIGURE 1. HC AND HCU TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

FIGURE 2. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

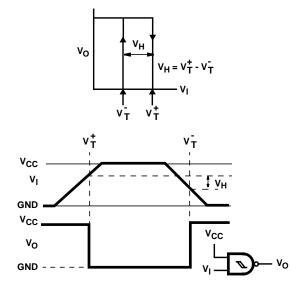


FIGURE 3. HYSTERESIS DEFINITION, CHARACTERISTIC, AND TEST SET-UP





2-Nov-2020

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-8984501CA	ACTIVE	CDIP	J	14	1	TBD	SNPB	N / A for Pkg Type	-55 to 125	5962-8984501CA CD54HCT132F3A	Samples
CD54HC132F3A	ACTIVE	CDIP	J	14	1	TBD	SNPB	N / A for Pkg Type	-55 to 125	CD54HC132F3A	Samples
CD54HCT132F	ACTIVE	CDIP	J	14	1	TBD	SNPB	N / A for Pkg Type	-55 to 125	CD54HCT132F	Samples
CD54HCT132F3A	ACTIVE	CDIP	J	14	1	TBD	SNPB	N / A for Pkg Type	-55 to 125	5962-8984501CA CD54HCT132F3A	Samples
CD74HC132E	ACTIVE	PDIP	N	14	25	Green (RoHS & no Sb/Br)	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC132E	Samples
CD74HC132EE4	ACTIVE	PDIP	N	14	25	Green (RoHS & no Sb/Br)	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC132E	Samples
CD74HC132M	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC132M	Samples
CD74HC132M96	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	NIPDAU SN	Level-1-260C-UNLIM	-55 to 125	HC132M	Samples
CD74HC132ME4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC132M	Samples
CD74HC132MT	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC132M	Samples
CD74HCT132E	ACTIVE	PDIP	N	14	25	Green (RoHS & no Sb/Br)	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT132E	Samples
CD74HCT132M	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT132M	Samples
CD74HCT132M96	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT132M	Samples
CD74HCT132MT	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT132M	Samples
CD74HCT132MTE4	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT132M	Samples

⁽¹⁾ The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PACKAGE OPTION ADDENDUM



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PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF CD54HC132, CD54HC132, CD74HC132, CD74HC132;

Catalog: CD74HC132, CD74HCT132

Military: CD54HC132, CD54HCT132

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

"All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC132M96	SOIC	D	14	2500	330.0	16.4	6.6	9.3	2.1	8.0	16.0	Q1
CD74HC132M96	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD74HC132MT	SOIC	D	14	250	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD74HCT132M96	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD74HCT132MT	SOIC	D	14	250	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1

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*All dimensions are nominal

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC132M96	SOIC	D	14	2500	366.0	364.0	50.0
CD74HC132M96	SOIC	D	14	2500	367.0	367.0	38.0
CD74HC132MT	SOIC	D	14	250	210.0	185.0	35.0
CD74HCT132M96	SOIC	D	14	2500	367.0	367.0	38.0
CD74HCT132MT	SOIC	D	14	250	210.0	185.0	35.0

CERAMIC DUAL IN LINE PACKAGE



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4040083-5/G





CERAMIC DUAL IN LINE PACKAGE



- 1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This package is hermitically sealed with a ceramic lid using glass frit.
- His package is remitted by sealed with a ceramic its using glass mit.
 Index point is provided on cap for terminal identification only and on press ceramic glass frit seal only.
 Falls within MIL-STD-1835 and GDIP1-T14.



CERAMIC DUAL IN LINE PACKAGE



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



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